


SURFACE MOUNTABLE PHASE CONTROL SCR

Description/Features

The 16TTS..S **SAFEIR** series of silicon controlled rectifiers are specifically designed for medium power switching and phase control applications. The glass passivation technology used has reliable operation up to 125° C junction temperature.

Typical applications are in input rectification (soft start) and these products are designed to be used with International Rectifier input diodes, switches and output rectifiers which are available in identical package outlines.

	$V_T < 1.4V @ 10A$
	$I_{TSM} = 200A$
	$V_{RRM} = 800 \text{ to } 1600V$

Output Current in Typical Applications

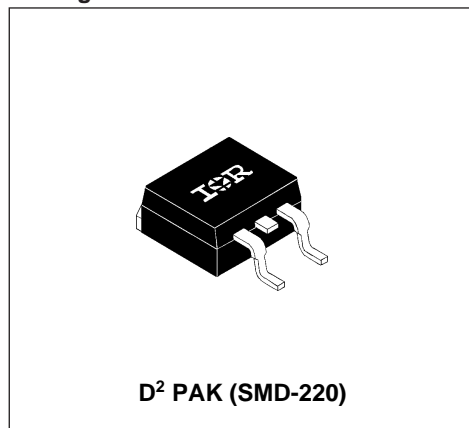
Applications	Single-phase Bridge	Three-phase Bridge	Units
NEMA FR-4 or G10 glass fabric-based epoxy with 4 oz (140µm) copper	2.5	3.5	A
Aluminum IMS, $R_{thCA} = 15^\circ C/W$	6.3	9.5	
Aluminum IMS with heatsink, $R_{thCA} = 5^\circ C/W$	14.0	18.5	

$T_A = 55^\circ C$, $T_J = 125^\circ C$, footprint 300mm²

Major Ratings and Characteristics

Characteristics	16TTS..S	Units
$I_{T(AV)}$ Sinusoidal waveform	10	A
I_{RMS}	16	A
V_{RRM}/V_{DRM}	up to 1600	V
I_{TSM}	200	A
$V_T @ 10 A, T_J = 25^\circ C$	1.4	V
dv/dt	500	V/µs
di/dt	150	A/µs
T_J	-40 to 125	°C

Package Outline



Voltage Ratings

Part Number	V_{RRM} , maximum peak reverse voltage V	V_{DRM} , maximum peak direct voltage V	I_{RRM}/I_{DRM} 125°C mA
16TTS08S	800	800	10
16TTS12S	1200	1200	
16TTS16S	1600	1600	

Absolute Maximum Ratings

Parameters	16TTS..S	Units	Conditions
$I_{T(AV)}$ Max. Average On-state Current	10	A	@ $T_C = 98^\circ\text{C}$, 180° conduction half sine wave
I_{RMS} Max. RMS On-state Current	16		
I_{TSM} Max. Peak One Cycle Non-Repetitive Surge Current	170		10ms Sine pulse, rated V_{RRM} applied
	200	10ms Sine pulse, no voltage reapplied	
I^2t Max. I^2t for fusing	144	A^2s	10ms Sine pulse, rated V_{RRM} applied
	200		10ms Sine pulse, no voltage reapplied
$I^2\sqrt{t}$ Max. $I^2\sqrt{t}$ for fusing	2000	$A^2\sqrt{s}$	$t = 0.1$ to 10ms, no voltage reapplied
V_{TM} Max. On-state Voltage Drop	1.4	V	@ 10A, $T_J = 25^\circ\text{C}$
r_t On-state slope resistance	24.0	m Ω	$T_J = 125^\circ\text{C}$
$V_{T(TO)}$ Threshold Voltage	1.1	V	
I_{RM}/I_{DM} Max. Reverse and Direct Leakage Current	0.5	mA	$T_J = 25^\circ\text{C}$
	10		$T_J = 125^\circ\text{C}$
I_H Holding Current	Typ.	mA	Anode Supply = 6V, Resistive load, Initial $I_T = 1A$ 16TTS08S, 16TTS12S 16TTS16S
	Max.		
	--		
	100		
	150		
I_L Max. Latching Current	200	mA	Anode Supply = 6V, Resistive load
dv/dt Max. Rate of Rise of off-state Voltage	500	V/ μs	
di/dt Max. Rate of Rise of turned-on Current	150	A/ μs	

Triggering

Parameters	16TTS..S	Units	Conditions
P_{GM} Max. peak Gate Power	8.0	W	
$P_{G(AV)}$ Max. average Gate Power	2.0		
$+I_{GM}$ Max. peak positive Gate Current	1.5	A	
$-V_{GM}$ Max. peak negative Gate Voltage	10	V	
I_{GT} Max. required DC Gate Current to trigger	90	mA	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	60		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	35		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
V_{GT} Max. required DC Gate Voltage to trigger	3.0	V	Anode supply = 6V, resistive load, $T_J = -10^\circ\text{C}$
	2.0		Anode supply = 6V, resistive load, $T_J = 25^\circ\text{C}$
	1.0		Anode supply = 6V, resistive load, $T_J = 125^\circ\text{C}$
V_{GD} Max. DC Gate Voltage not to trigger	0.25		$T_J = 125^\circ\text{C}$, $V_{DRM} = \text{rated value}$
I_{GD} Max. DC Gate Current not to trigger	2.0	mA	$T_J = 125^\circ\text{C}$, $V_{DRM} = \text{rated value}$

Switching

Parameters	16TTS..S	Units	Conditions
t_{gt} Typical turn-on time	0.9	μs	$T_J = 25^\circ\text{C}$
t_{rr} Typical reverse recovery time	4		$T_J = 125^\circ\text{C}$
t_q Typical turn-off time	110		

Thermal-Mechanical Specifications

Parameters	16TTS..S	Units	Conditions
T_J Max. Junction Temperature Range	-40 to 125	$^\circ\text{C}$	
T_{stg} Max. Storage Temperature Range	-40 to 125	$^\circ\text{C}$	
	Soldering Temperature	240	$^\circ\text{C}$ for 10 seconds (1.6mm from case)
R_{thJC} Max. Thermal Resistance Junction to Case	1.3	$^\circ\text{C}/\text{W}$	DC operation
R_{thJA} Typ. Thermal Resistance Junction to Ambient (PCB Mount)**	40	$^\circ\text{C}/\text{W}$	
wt Approximate Weight	2 (0.07)	g(oz.)	
T Case Style	D ² Pak (SMD-220)		

**When mounted on 1" square (650mm²) PCB of FR-4 or G-10 material 4 oz (140 μm) copper 40 $^\circ\text{C}/\text{W}$
 For recommended footprint and soldering techniques refer to application note #AN-994

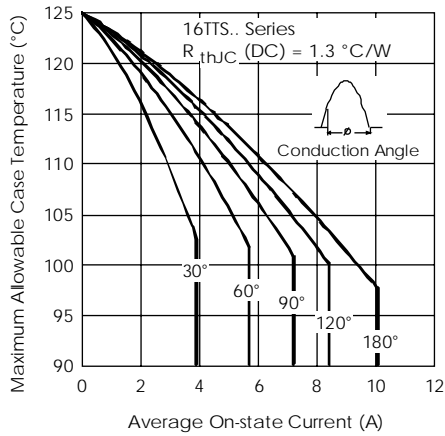


Fig. 1 - Current Rating Characteristics

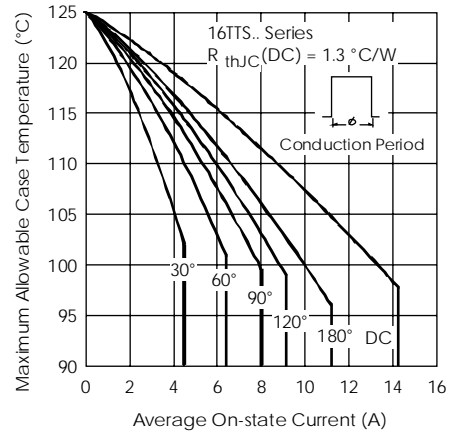


Fig. 2 - Current Rating Characteristics

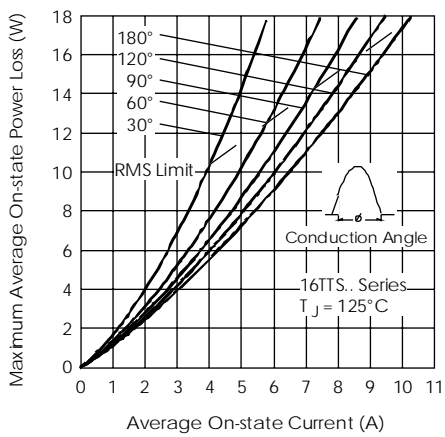


Fig. 3 - On-state Power Loss Characteristics

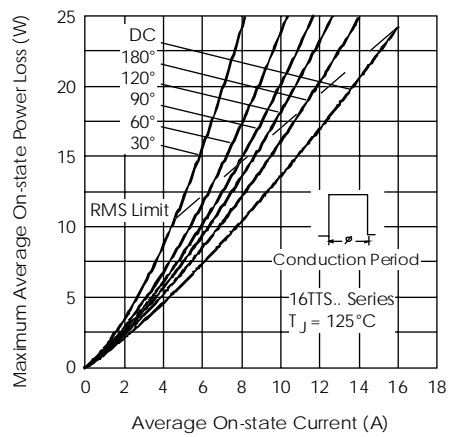


Fig. 4 - On-state Power Loss Characteristics

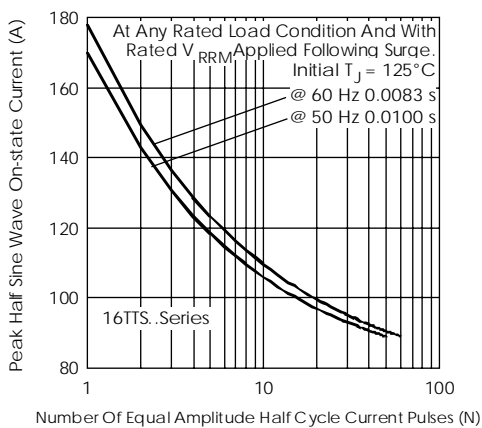


Fig. 6 - Maximum Non-Repetitive Surge Current

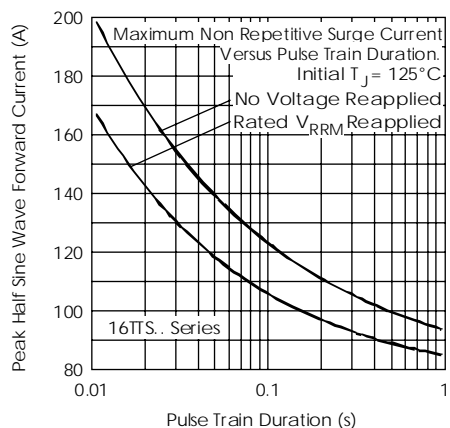


Fig. 7 - Maximum Non-Repetitive Surge Current

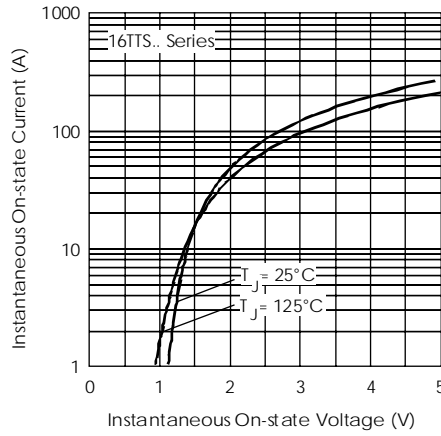


Fig. 7 - On-state Voltage Drop Characteristics

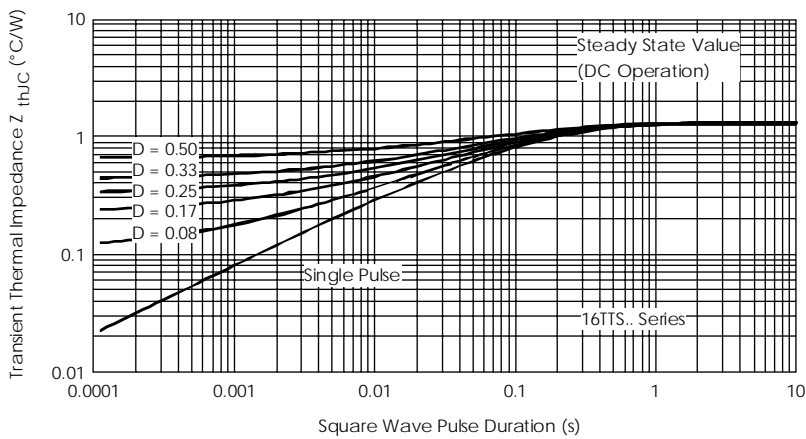


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

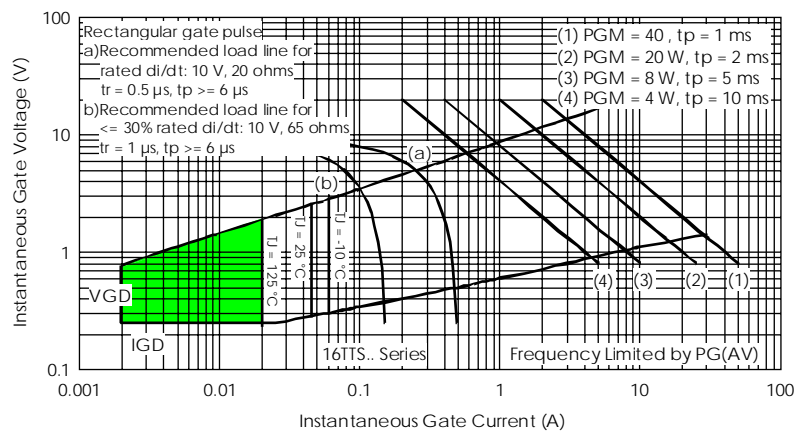
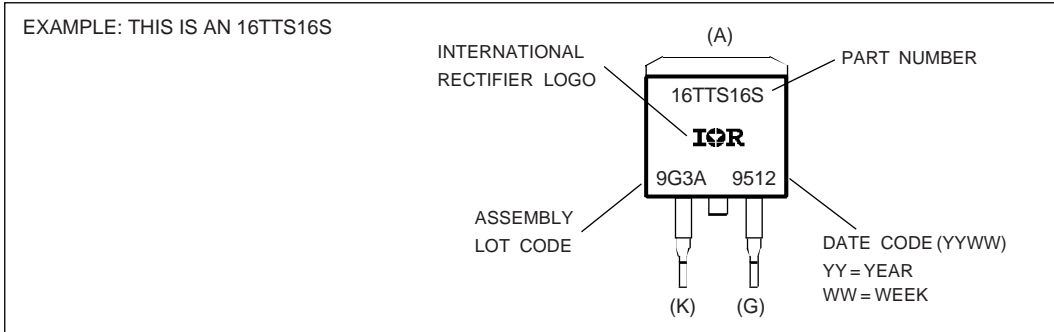
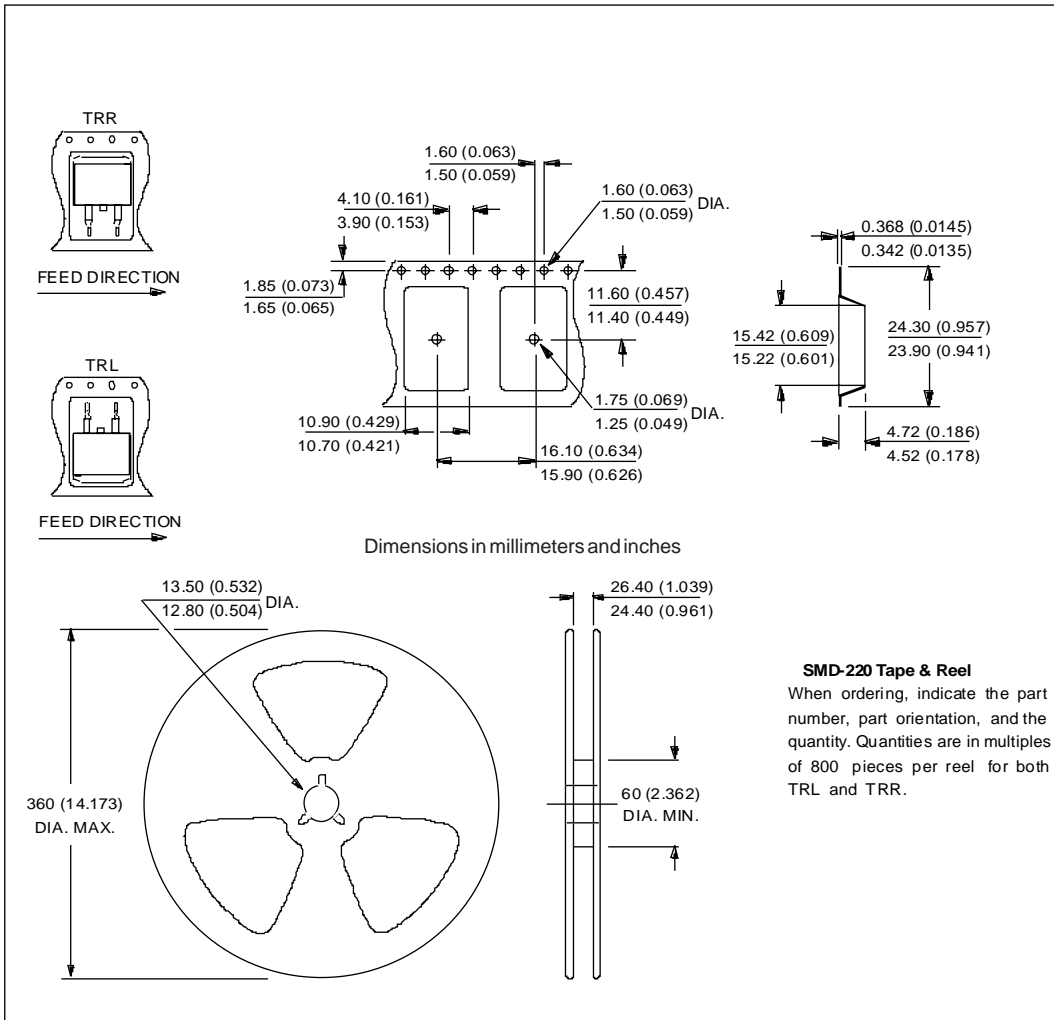


Fig. 9 - Gate Characteristics

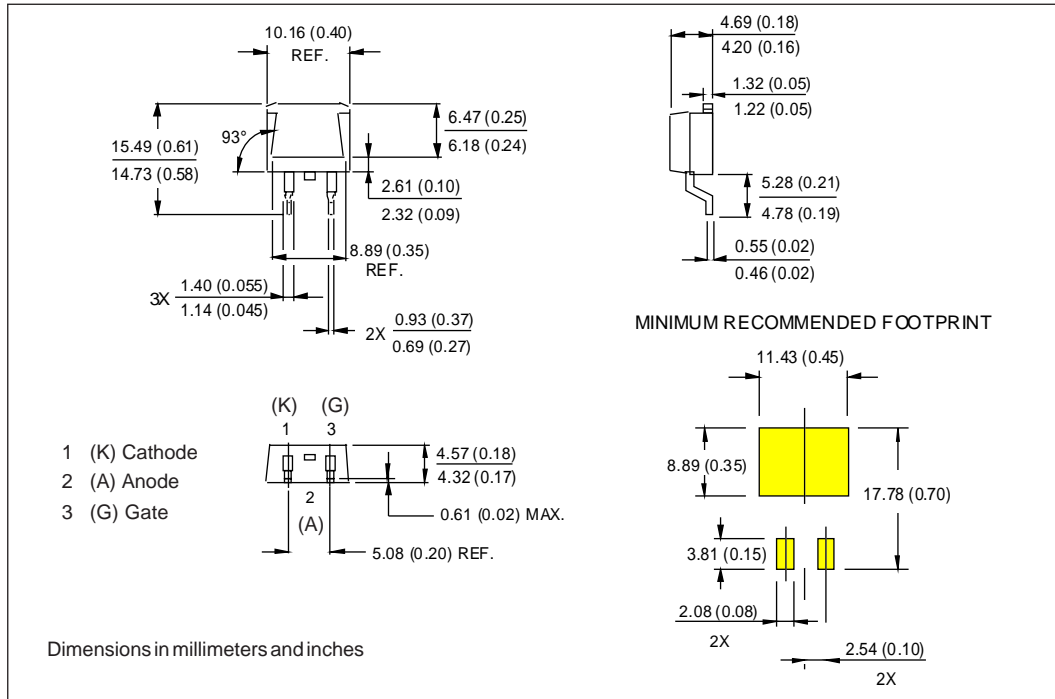
Marking Information



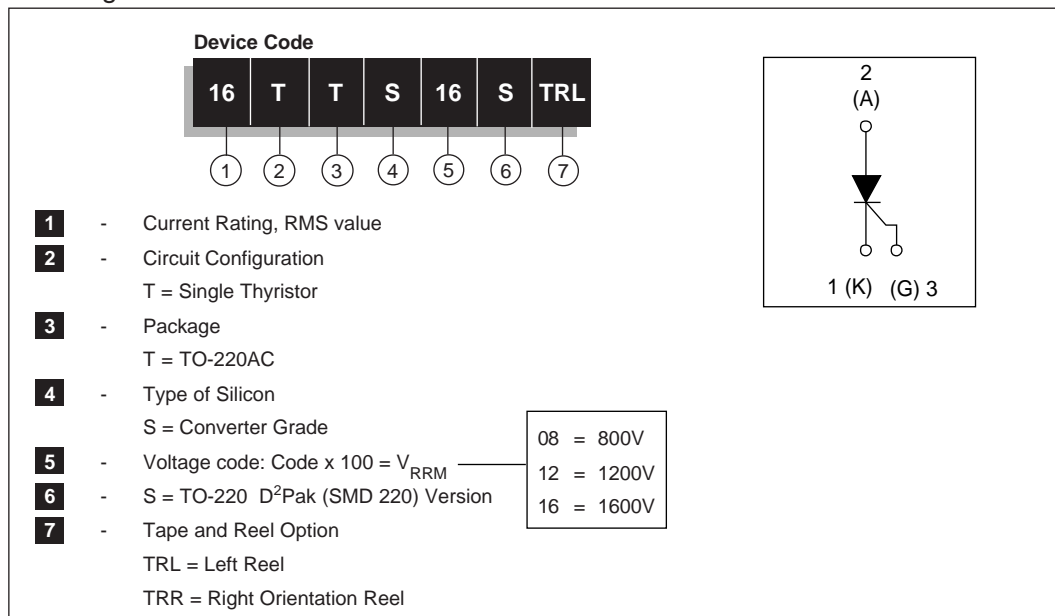
Tape & Reel Information



Outline Table



Ordering Information Table



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IR CANADA: 15 Lincoln Court, Brampton, Markham, Ontario L6T3Z2. Tel: (905) 453 2200. Fax: (905) 475 8801.
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IR ITALY: Via Liguria 49, 10071 Borgaro, Torino. Tel: ++ 39 11 4510111. Fax: ++ 39 11 4510220.
IR FAR EAST: K&H Bldg., 2F, 30-4 Nishi-Ikebukuro 3-Chome, Toshima-Ku, Tokyo, Japan 171. Tel: 81 3 3983 0086.
IR SOUTHEAST ASIA: 1 Kim Seng Promenade, Great World City West Tower, 13-11, Singapore 237994. Tel: ++ 65 838 4630.
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